

## isc Triacs

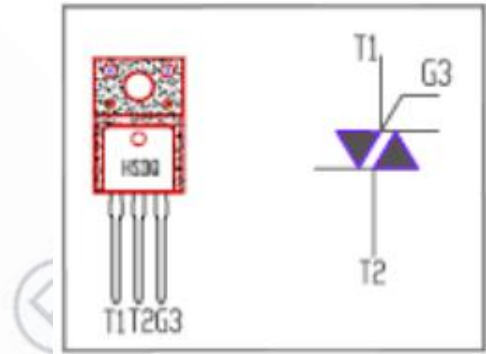
## TMA166S-L

## APPLICATIONS

- Residential and commercial appliances: vacuum cleaners, rice cookers, TVs, home entertainment
- White goods: washing machines
- Office automation power control, photocopiers
- Motor control for small tools
- Temperature control, light dimmers, electric blankets
- General use switching mode power supplies (SMPS)

## FEATURES

- $I_T$  (RMS) : 16 A
- $V_{DRM}$  : 600 V
- $I_{FGT}$ ,  $I_{RGT}$ ,  $I_{RGTIII}$  : 30mA
- Insulated Type



## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL        | PARAMETER   | Value   | UNIT             |
|---------------|---|---------|------------------|
| $V_{DRM}$     | Repetitive peak off-state voltage   | 600     | V                |
| $V_{RRM}$     | Repetitive peak reverse voltage   | 600     | V                |
| $I_{T(RMS)}$  | RMS on-state current (full sine wave) $T_c=80^\circ\text{C}$  | 16      | A                |
| $I_{TSM}$     | Non repetitive surge peak on-state current (half sine cycle, $T_j=25^\circ\text{C}$ ) $F=50\text{HZ}$ $t=20\text{ms}$                           | 160     | A                |
| $I_{GM}$      | Peak gate current $t_p=20\mu\text{s}$ , $T_j=125^\circ\text{C}$   | 4       | A                |
| $I^2t$        | $I^2t$ Value for fusing $t_p=10\text{ms}$   | 144     | A <sup>2</sup> S |
| $P_{G(AV)}$   | Average gate power dissipation  | 1       | W                |
| $di/dt$       | Repetitive rate of rise of on-state current after triggering<br>$I_{TM}=20\text{A}$ $I_G=70\text{mA}$ $dI_G/dt$ 50mA/ms $T_j=125^\circ\text{C}$ | 50      | A/ $\mu\text{s}$ |
| $T_j$         | Operating junction temperature  | -40-125 | °C               |
| $T_{stg}$     | Storage temperature   | -40~150 | °C               |
| $R_{th(j-c)}$ | Thermal resistance, junction to case  | 1.3     | °C/W             |

isc Triacs

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**ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25°C unless otherwise specified)**

| SYMBOL               | PARAMETER  |              | CONDITIONS   | MIN  | MAX      | UNIT |
|----------------------|--|--------------|--|------|----------|------|
| I <sub>RRM</sub>     | Repetitive peak reverse current                              |              | V <sub>R</sub> =V <sub>RRM</sub> ,<br>V <sub>R</sub> =V <sub>RRM</sub> , T <sub>J</sub> =125°C |      | 0.1<br>2 | mA   |
| I <sub>DRM</sub>     | Repetitive peak off-state current                            |              | V <sub>D</sub> =V <sub>DRM</sub> ,<br>V <sub>D</sub> =V <sub>DRM</sub> , T <sub>J</sub> =125°C |      | 0.1<br>2 | mA   |
| I <sub>GT</sub>      | Gate trigger current   | I - II - III | V <sub>D</sub> =12V; R <sub>L</sub> = 20 Ω   |      | 30       | mA   |
| I <sub>H</sub>       | Holding current  |              | I <sub>GT</sub> = 0.5A,  |      | 60       | mA   |
| V <sub>GT</sub>      | Gate trigger voltage   | I - II - III | V <sub>D</sub> =12V; R <sub>L</sub> = 20 Ω   |      | 1.5      | V    |
| dv/dt                |  |              | V <sub>D</sub> =67% V <sub>DRM</sub> gate open(T <sub>J</sub> =125°C)                          | 1000 |          | V/us |
| (dv/dt) <sub>c</sub> | Critical Rising Rate of Off-State Voltage during Commutation |              | T <sub>J</sub> =125°C  | 10   |          | V/us |
| V <sub>TM</sub>      | On-state voltage   |              | I <sub>TM</sub> =32A , tp=380μs  |      | 1.5      | V    |

**TO-220F outline dimensional drawing**

